

Rev 1.0 27/12/22

Ultra-Fast recovery rectifier diode in bare die form

Features:

- Low leakage current
- High forward surge current capability
- Low forward voltage drop
- Robust construction
- High reliability tested grades.

Ordering Information

The following part suffixes apply:

- No suffix MIL-STD-750 /2073 Visual Inspection
- "H" MIL-STD-750 /2073 Visual Inspection+ MIL-PRF-38534 Class H LAT
- "K" MIL-STD-750 /2073 Visual Inspection+ MIL-PRF-38534 Class K LAT

LAT = Lot Acceptance Test.

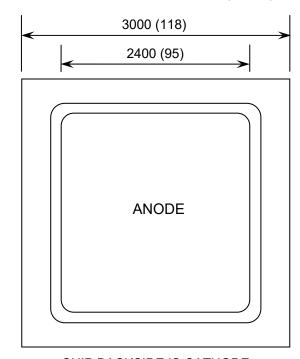
For further information on LAT process flows see below.

www.siliconsupplies.com\quality\bare-die-lot-qualification

Supply Formats:

- Default Die in Waffle Pack (100 per tray capacity)
- Sawn Wafer on Tape By specific request
- Unsawn Wafer By specific request
- With additional electrical selection By specific request

Die Dimensions in µm (mils)



CHIP BACKSIDE IS CATHODE



Mechanical Specification

Die Size (Unsawn)	3000 x 3000 118.11 x 118.11	μm mils	
Anode Pad Size	2400 x 2400 94.49 x 94.49	μm mils	
Die Thickness	220 (±20) 8.66 (±0.79)		
Top Metal Composition	Al 7.5μm		
Back Metal Composition	Ti/Ni/Ag 2.5µm		





Rev 1.0 27/12/22

Absolute Maximum Ratings¹ T_J = 25°C unless otherwise stated

PARAMETER	SYMBOL	VALUE	UNIT	
Peak Repetitive Reverse Voltage	V_{RRM}			
Working Peak Repetitive Reverse Voltage	V _{RWM}	400	V	
DC Blocking Voltage	V _R			
RMS Reverse Voltage	V _{R (RMS)}	280	V	
Average Forward Rectified Current, T _J = 150°C	I _{F(AV)}	15	А	
Peak Repetitive Forward Current ²	I _{FM}	30	Α	
Non-Repetitive Peak Forward Surge Current ³	I _{FSM}	225	А	
Operating Junction temperature	T _J	-55 to 175	°C	
Storage Temperature Range	T _{STG}	-65 to 175	°C	

Electrical Characteristics T_J = 25°C unless otherwise stated

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Maximum Instantaneous Forward Voltage ⁴ V _F	I _F = 15A, T _J = 25°C	-	-	1.25	V	
	* F	I _F = 15A, T _J = 125°C	-	-	1.12	V
Maximum Instantaneous Reverse Leakage Current ⁴ I _{RM} @ V _{RRM}	Inu @ Vanu	V _{RRM} = 400V, T _J = 25°C	-	0.005	0.05	μА
	IRM @ VRRM	V _{RRM} = 400V, T _J = 125°C	-	5	20	
Reverse Recovery Time	t _{rr}	I _F = 0.5A, I _R = 1.0A, I _{rr} = 0.25A	-	33	60	ns
Junction Capacitance	Сл	V _R = 4V, f = 1.0MHz	-	100	-	pF

^{1.} Operation above the absolute maximum rating may cause device failure. Operation at the absolute maximum ratings, for extended periods, may reduce device reliability. 2. V_R = 400V, Square Wave, 20kHz Pulse Width = 3.8ms 3. Surge applied at rated load conditions halfwave, single phase, 60Hz 4. Pulse Test: Pulse Width = 300s, Duty Cycle ≤ 2.0%

Typical Characteristics T_J = 25°C unless otherwise stated

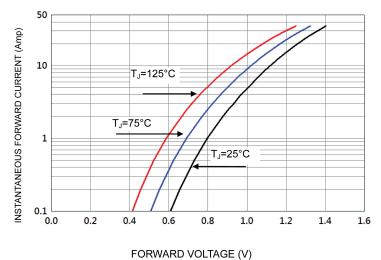


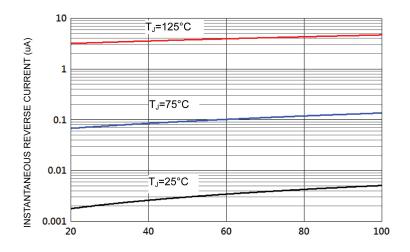
FIGURE 1. Forward Voltage Characteristics





Typical Characteristics Continued T_J = 25°C unless otherwise stated

Rev 1.0 27/12/22



PERCENT OF RATED PEAK REVERSE VOLTAGE (%)

FIGURE 2. Reverse Current Versus Reverse Voltage



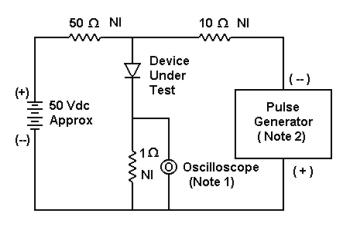
FIGURE 3. Peak Forward Surge Current Versus Cycles at 60 Hz

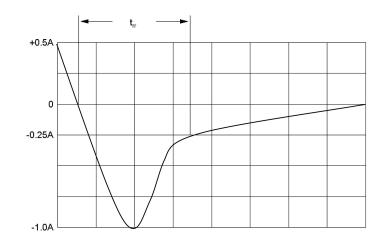




Typical Characteristics Continued T_J = 25°C unless otherwise stated

Rev 1.0 27/12/22





Notes:

- 1. Rise Time = 7 ns max. Input Impedance = 1 M Ω , 22 pF
- 2. Rise Time = 10 ns max. Input Impedance = 50Ω

Set time base for 10/20 ns/cm



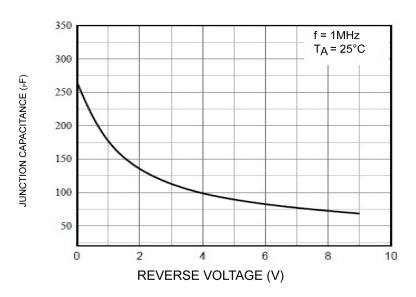


FIGURE 5. Typical Junction Capacitance

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